

# **Preliminary Datasheet**

#### N+P-Channel 20-V (D-S) MOSFET

#### **FEATURES**

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

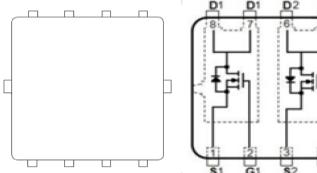
## **Application**

- Portable Devices
- ■Consumer Electronics

#### **Mechanical**

●Case: DFN3333 Package

PRODUCTY SUMMARY						
$V_{DS}$	R	$_{DS(on)}m(\Omega)$	I <sub>D</sub> (A)			
20	6	@V <sub>GS</sub> =4.5V	20			
20	7.3	@V <sub>GS</sub> =2.5V	20			
20	15	@V <sub>GS</sub> =-4.5V	-17			
-20	18	@V <sub>GS</sub> =-2.5V	-16			



## **Packing Information**

Package	Packing		
DFN3333	5Kpcs/13"Reel		

Maximum Ratings (T <sub>A</sub> =25°C unless otherwise specified)							
Parameter	Symbol	Lin	Unit				
		N-Channel	P-Channel				
Drain-Source Voltage	$V_{DS}$	20	-20	V			
Gate-Source Voltage	$V_{GS}$	±12	±12	V			
Continuous Drain Current 1)	I <sub>D</sub>	20	-17	А			
Maximum Power Dissipation	$P_{D}$	5	5	W			
Pulsed Drain Current 2)	I <sub>DM</sub>	80	-68	А			
ng Junction and Storage Temperature	T <sub>J</sub> , T <sub>STG</sub>	-55 to 150	-55 to 150	°C			

Typical Thermal Resistance						
Parameter Symbol Limit Unit						
Junction-to-Ambient Thermal Resistance	$R_{\theta JA}$	65	°C/W			

### Note:

 $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper



Electrical Characteristics (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)						
Characteristics	Symbol	Test Condition	Limits			l loi4
Characteristics			Min	Тур	Max	Unit
	N	-Channel Static				
Drain-Source Breakdown Voltage	$B_{VDSS}$	$V_{GS} = 0V, I_{D} = 250uA$	20			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	0.40	0.62	1.00	V
	R <sub>DS(on)</sub>	$V_{GS}$ =4.5V, $I_D$ =20A	-	5.1	6.0	mΩ
Drain-Source On-State Resistance		V <sub>GS</sub> =2.5V, ID=20A	-	6.2	7.3	mΩ
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =20V, $V_{GS}$ =0V	-	-	1.0	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm 12V, V_{DS}=0V$	-	-	±100	nA
Drain-Source Diode						
Maximum Continuous Body Diode Forward Current	I <sub>S</sub>	V <sub>G</sub> =V <sub>D</sub> =0V , Force Current	-	-	1.2	А
Diode Forward Voltage	$V_{\text{SD}}$	IS=1.0A, VGS=0V	-	-	1.5	V

Electrical Characteristics (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)						
Characteristics	Symbol	Test Condition	Limits			Unit
Characteristics			Min	Тур	Max	Onit
	Р	-Channel Static				
Drain-Source Breakdown Voltage	$B_{VDSS}$	$V_{GS} = 0V, I_{D} = -250uA$	-20			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-0.50	-0.70	-1.00	V
Dunin Course On Otata Basistanas	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-17A	ı	13	15	mΩ
Drain-Source On-State Resistance		V <sub>GS</sub> =-2.5V, ID=-16A	ı	15	18	mΩ
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V	1	1	1.0	uA
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 12V, V_{DS}=0V$	-	-	±100	nA
Drain-Source Diode						
Maximum Continuous Body Diode Forward Current	Is	$V_G=V_D=0V$ , Force Current	-	-	-1.2	А
Diode Forward Voltage	$V_{SD}$	IS=-1.0A, VGS=0V	•	ı	-1.5	V

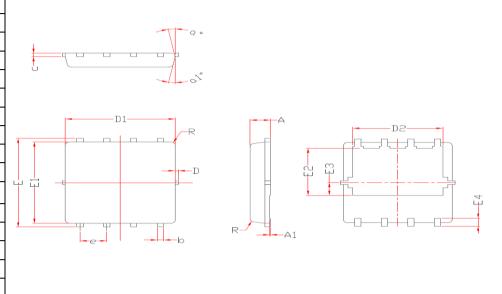
#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature  $T_J(MAX)=150^{\circ}C$ . Ratings are based on low frequency and duty cycles to keep initial  $T_J=25^{\circ}C$ .
- 4. The maximum current rating is package limited.
- 5. RQJA is the sum of the junctiontocase and casetoambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch2 with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.

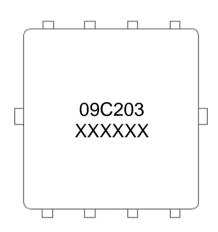


## Package Outline Dimensions (inches and millimeters)

	Dimensions					
SYMBOL	Millim	neters	Inches			
	Min	Max	Min	Max		
Α	0.78	0.82	0.031	0.032		
A1	0.00	0.05	0.000	0.002		
b	0.30	0.35	0.012	0.014		
С	0.	15	0.006			
D	0.00	0.05	0.000	0.002		
D1	2.98	3.03	0.117	0.119		
D2	2.3	35	0.093			
E	3.20	3.25	0.126	0.128		
E1	2.98	3.03	0.117	0.119		
E2	1.7	75	0.069			
E3	0.5	58	0.023			
E4	0.350	0.45	0.014	0		
R	0.20 0.008					
е	0.65BSC					
a°	3°					
a1°	10°					



# **Marking Information**



First line:

AAAAAA = Product number

Second line:

XXXXXX = Tracking number

Third line:Gate Pin Point

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